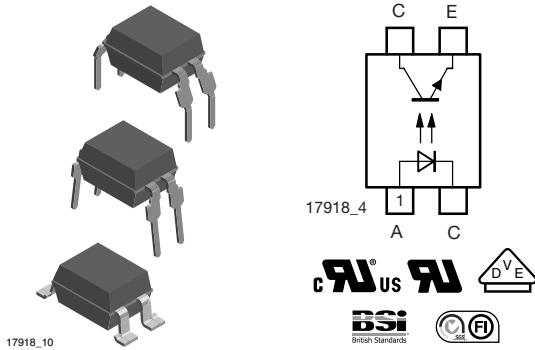


Optocoupler, Phototransistor Output, High Temperature, 110 °C Rated



DESCRIPTION

The VO615A consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin plastic dual inline package.

AGENCY APPROVALS

- BSI: EN 60065:2002, EN 60950-1:2006
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- FIMKO
- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A

FEATURES

- CTR offered in 9 groups
- Isolation materials according to UL 94 V-0
- Pollution degree 2 (DIN/VDE 0110/resp. IEC 60664)
- Climatic classification 55/110/21 (IEC 60068 part 1)
- Temperature range - 55 °C to + 110 °C
- Rated impulse voltage (transient overvoltage) $V_{IOTM} = 6 \text{ kV}_{\text{peak}}$
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6 \text{ kV}$
- Rated isolation voltage (RMS includes DC) $V_{IOWM} = 600 \text{ V}_{\text{RMS}}$
- Rated recurring peak voltage (repetitive) $V_{IORM} = 850 \text{ V}_{\text{peak}}$
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: $\text{CTI} \geq 250$
- Compliant to RoHS Directive 2002/95/EC


**RoHS
COMPLIANT**

APPLICATIONS

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- for appl. class I - IV at mains voltage $\leq 300 \text{ V}$
- for appl. class I - IV at mains voltage $\leq 600 \text{ V}$ according to table 1 of IEC 60664-1, suitable for:
 - Switch-mode power supplies
 - Line receiver
 - Computer peripheral interface
 - Microprocessor system interface

ORDERING INFORMATION

PART NUMBER	CTR BIN	PACKAGE OPTION	TAPE AND REEL
V O 6 1 5 A - # X 0 # # T			DIP-# 7.62 mm Option 6 10.16 mm Option 7 > 0.7 mm Option 8 9.27 mm Option 9 > 0.1 mm

AGENCY CERTIFIED/ PACKAGE	CTR (%)									
	5 mA	10 mA				5 mA				
BSI, FIMKO, UL, cUL	50 to 600	40 to 80	63 to 125	100 to 200	160 to 320	50 to 150	100 to 300	80 to 160	130 to 260	200 to 400
DIP-4	VO615A	VO615A-1	VO615A-2	VO615A-3	VO615A-4	VO615A-5	VO615A-6	VO615A-7	VO615A-8	VO615A-9
DIP-4, 400 mil, option 6	VO615A-X006	VO615A-1X006	VO615A-2X006	VO615A-3X006	VO615A-4X006	VO615A-5X006	VO615A-6X006	VO615A-7X006	VO615A-8X006	VO615A-9X006
SMD-4, option 7	VO615A-X007T	VO615A-1X007T	VO615A-2X007T	VO615A-3X007T	VO615A-4X007T	VO615A-5X007T	VO615A-6X007T	VO615A-7X007T	VO615A-8X007T	VO615A-9X007T
SMD-4, option 9	VO615A-X009T	VO615A-1X009T	VO615A-2X009T	VO615A-3X009T	VO615A-4X009T	VO615A-5X009T	VO615A-6X009T	VO615A-7X009T	-	-
	50 to 600	40 to 80	63 to 125	100 to 200	160 to 320	50 to 150	100 to 300	80 to 160	130 to 260	200 to 400
DIP-4	VO615A-X001	VO615A-1X001	-	VO615A-3X001	-	-	VO615A-6X001	-	VO615A-8X001	-
DIP-4, 400 mil, option 6	-	-	VO615A-2X016	VO615A-3X016	VO615A-4X016	VO615A-5X016	-	-	VO615A-8X016	VO615A-9X016
SMD-4, option 7	VO615A-X017T	VO615A-1X017T	-	VO615A-3X017T	VO615A-4X017T	-	VO615A-6X017T	-	VO615A-8X017T	VO615A-9X017T
SMD-4, option 8	-	-	-	VO615A-3X018T	VO615A-4X018T	-	-	-	-	-
SMD-4, option 9	-	-	VO615A-2X019T	VO615A-3X019T	VO615A-4X019T	-	-	-	-	-

Note

- Additional options may be possible, please contact sales office.

VO615A



Vishay Semiconductors Optocoupler, Phototransistor Output,
High Temperature, 110 °C Rated

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25$ °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	1.5	A
LED power dissipation	at 25 °C	P_{diss}	70	mW
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10$ ms	I_{CM}	100	mA
Output power dissipation	at 25 °C	P_{diss}	70	mW
COUPLER				
Isolation test voltage (RMS)	$t = 1$ s	V_{ISO}	5000	V_{RMS}
Operating ambient temperature range		T_{amb}	- 55 to + 110	°C
Storage temperature range		T_{stg}	- 55 to + 125	°C
Soldering temperature ⁽¹⁾	2 mm from case, ≤ 10 s	T_{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 50$ mA	V_F		1.43	1.6	V
Junction capacitance	$V_R = 0$, $f = 1$ MHz	C_j		50		pF
OUTPUT						
Collector emitter voltage	$I_C = 1$ mA	V_{CEO}	70			V
Emitter collector voltage	$I_E = 100$ µA	V_{ECO}	7			V
Collector emitter cut-off current	$V_{CE} = 20$ V, $I_F = 0$	I_{CEO}		10	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10$ mA, $I_C = 1$ mA	V_{CESat}			0.3	V
Cut-off frequency	$V_{CE} = 5$ V, $I_F = 10$ mA, $R_L = 100$ Ω	f_c		110		kHz
Coupling capacitance	$f = 1$ MHz	C_k		0.6		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

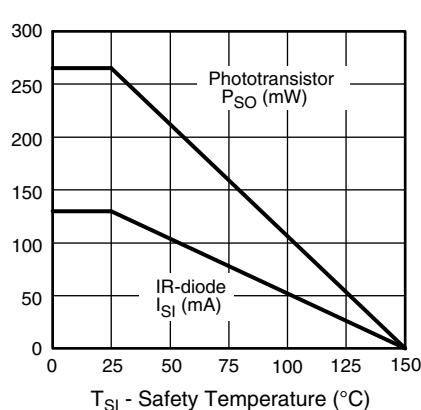
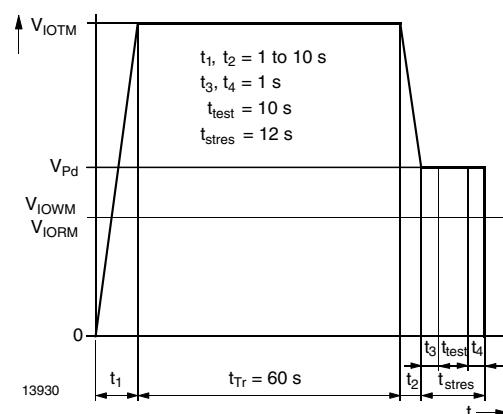
**Optocoupler, Phototransistor Output, Vishay Semiconductors
High Temperature, 110 °C Rated**

CURRENT TRANSFER RATIO ($T_{amb} = 25$ °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$V_{CE} = 5$ V, I _F = 1 mA	VO615A-1	CTR	13	30		%
		VO615A-2	CTR	22	45		%
		VO615A-3	CTR	34	70		%
		VO615A-4	CTR	56	90		%
	$V_{CE} = 5$ V, I _F = 5 mA	VO615A	CTR	50		600	%
		VO615A-5	CTR	50		150	%
		VO615A-6	CTR	100		300	%
		VO615A-7	CTR	80		160	%
		VO615A-8	CTR	130		260	%
	$V_{CE} = 5$ V, I _F = 10 mA	VO615A-9	CTR	200		400	%
		VO615A-1	CTR	40		80	%
		VO615A-2	CTR	63		125	%
		VO615A-3	CTR	100		200	%
		VO615A-4	CTR	160		320	%

SAFETY AND INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	1.6			kV
Partial discharge test voltage - lot test (sample test)	t _{Tr} = 60 s, t _{test} = 10 s, (see figure 2)	V _{pd}	1.36			kV
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω
Rated impulse voltage		V _{IOTM}			6	kV
Max. working voltages	Recurring peak voltage	V _{IORM}	850			V
Forward current		I _{SI}			130	mA
Power dissipation		P _{SO}			265	mW
Safety temperature		T _{si}			150	°C
Creepage distance					7.6	mm

Note

- According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.


Fig. 1 - Derating Diagram

Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Delay time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_d		3		μs
Rise time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_r		3		μs
Fall time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_f		4.7		μs
Storage time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_s		0.3		μs
Turn-on time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_{on}		6		μs
Turn-off time	$V_S = 5$ V, $I_C = 2$ mA, $R_L = 100$ Ω, (see figure 3)	t_{off}		5		μs
Turn-on time	$V_S = 5$ V, $I_F = 10$ mA, $R_L = 1$ kΩ, (see figure 4)	t_{on}		3		μs
Turn-off time	$V_S = 5$ V, $I_F = 10$ mA, $R_L = 1$ kΩ, (see figure 4)	t_{off}		10		μs

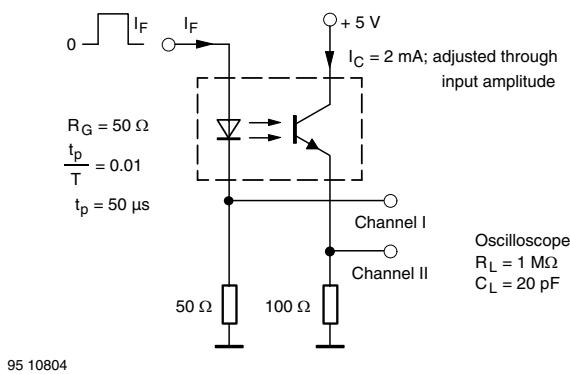


Fig. 3 - Test Circuit, Non-Saturated Operation

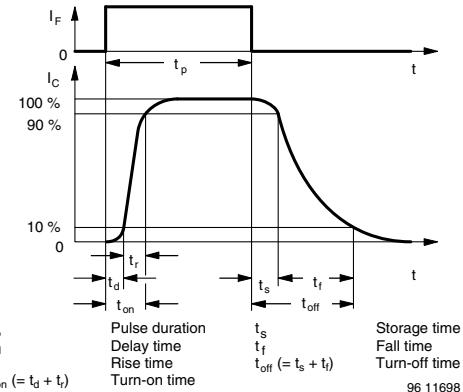


Fig. 5 - Switching Times

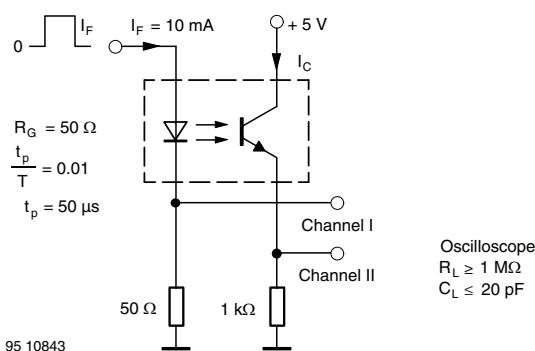


Fig. 4 - Test Circuit, Saturated Operation

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High Temperature, 110 °C Rated**

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

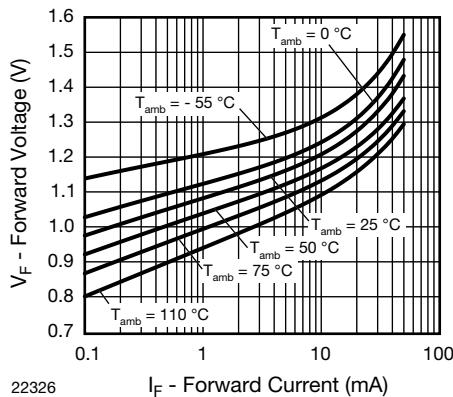


Fig. 6 - Forward Voltage vs. Forward Current

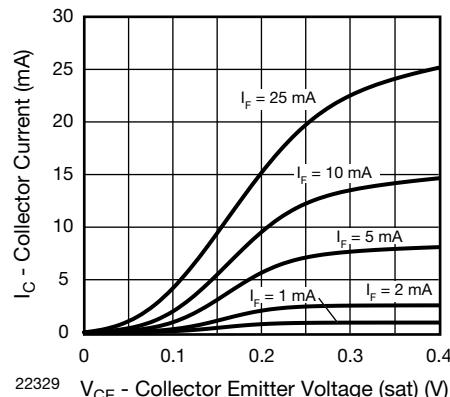


Fig. 9 - Collector Current vs. Collector Emitter Voltage (sat)

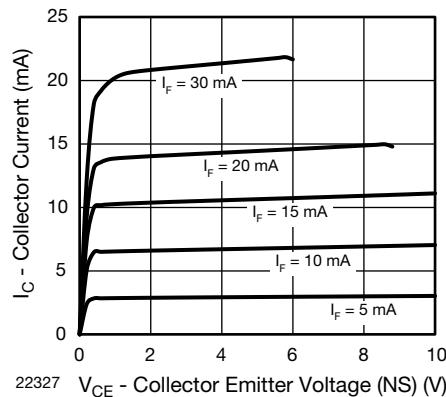


Fig. 7 - Collector Current vs. Collector Emitter Voltage (NS)

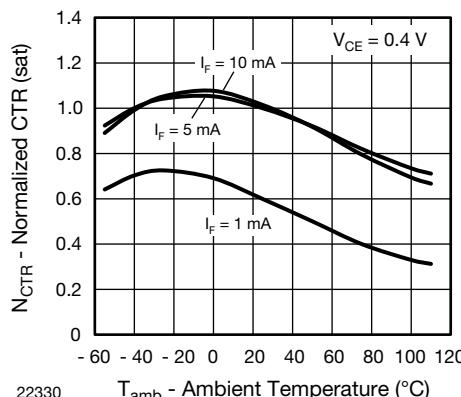


Fig. 10 - Normalized CTR (sat) vs. Ambient Temperature

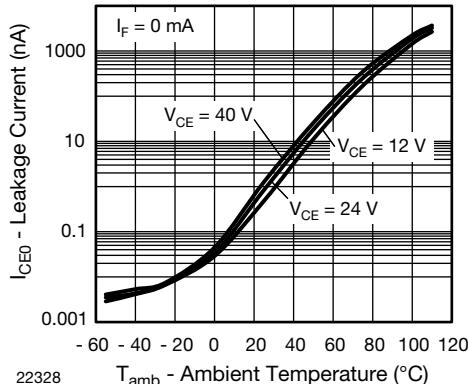


Fig. 8 - Leakage Current vs. Ambient Temperature

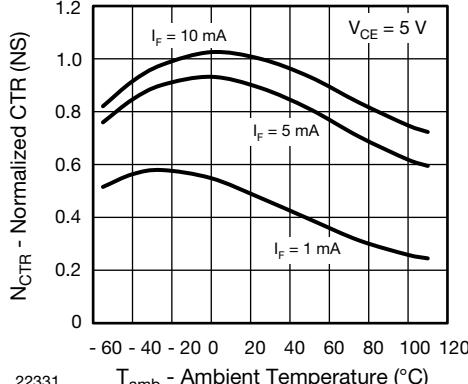


Fig. 11 - Normalized CTR (NS) vs. Ambient Temperature

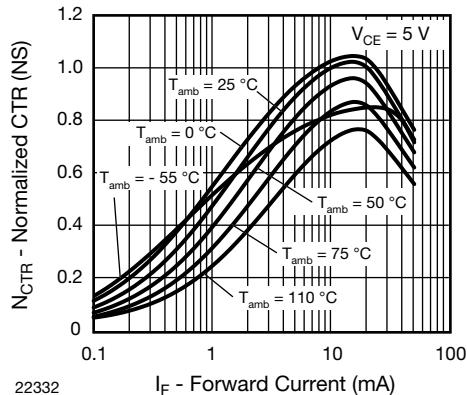


Fig. 12 - Normalized CTR (NS) vs. Forward Current

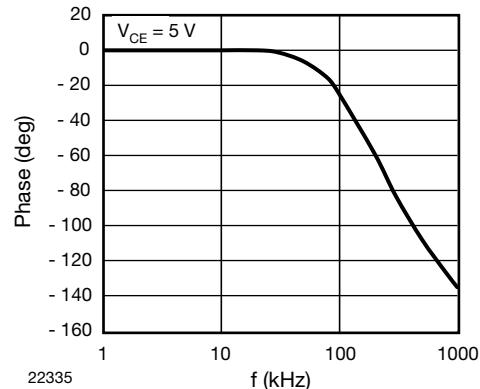
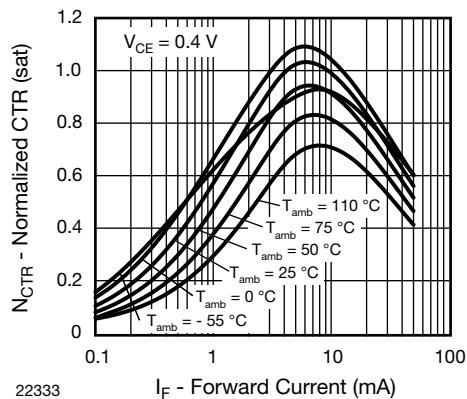
Fig. 15 - F_{CTR} vs. Phase Angle (kHz)

Fig. 13 - Normalized CTR (sat) vs. Forward Current

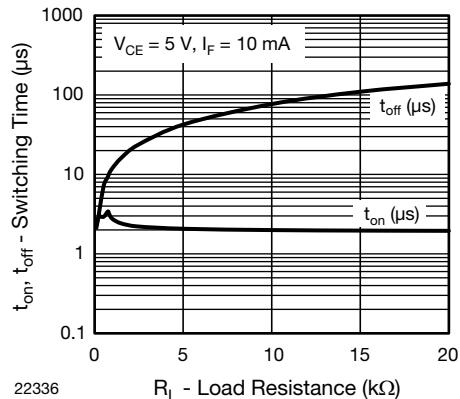
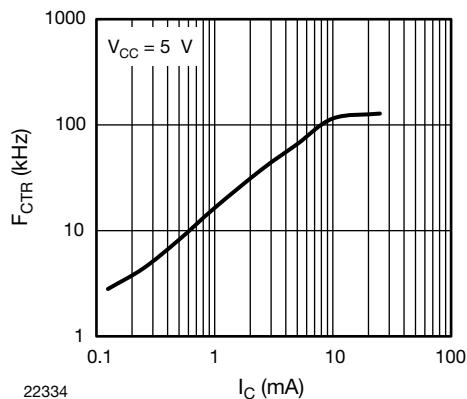
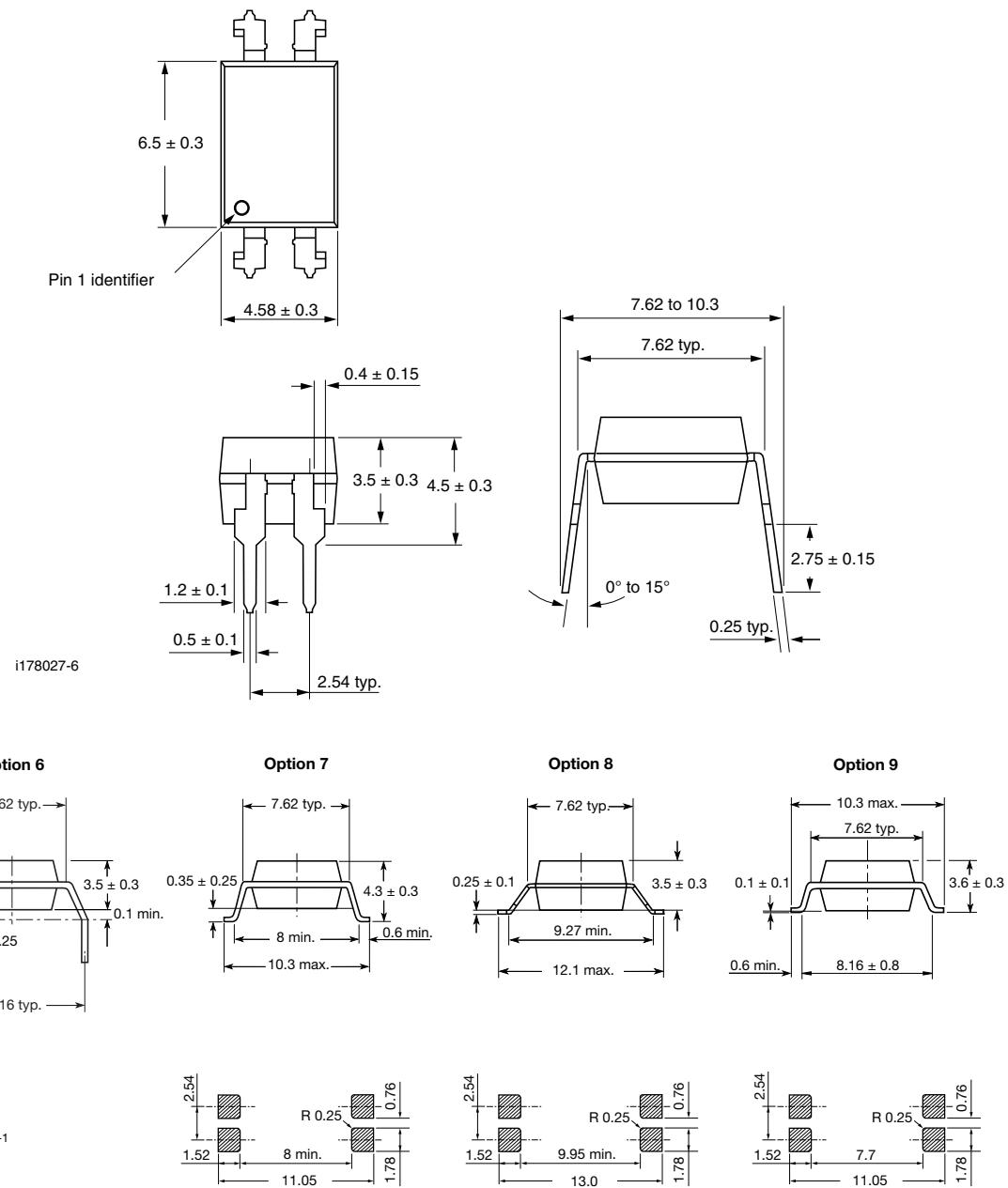
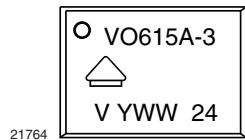


Fig. 16 - Switching Time vs. Load Resistance

Fig. 14 - F_{CTR} vs. I_C (sat) (mA)

PACKAGE DIMENSIONS in millimeters

PACKAGE MARKING

Notes

- Only options 1, 7 and 8 are reflected in the package marking.
- The VDE logo is only marked on option1 parts.
- Tape and reel suffix (T) is not part of the package marking.



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